

Electrical Characteristics
$T_{A}=25^{\circ} \mathrm{C}$ unless otherwise noted

| Symbol | Parameter | Test Conditions | Min | Max | Units |
| :--- | :--- | :--- | :--- | :--- | :--- |

OFF CHARACTERISTICS

| $\mathrm{V}_{\text {(BR)CEO }}$ | Collector-Emitter Breakdown Voltage $^{*}$ | $\mathrm{I}_{\mathrm{C}}=1.0 \mathrm{~mA}, \mathrm{I}_{\mathrm{B}}=0$ | 40 |  | V |
| :--- | :--- | :--- | :---: | :---: | :---: |
| $\mathrm{~V}_{\text {(BR)CBO }}$ | Collector-Base Breakdown Voltage | $\mathrm{I}_{\mathrm{C}}=10 \mu \mathrm{~A}, \mathrm{I}_{\mathrm{E}}=0$ | 40 |  | V |
| $\mathrm{~V}_{\text {(BR) }) \text { EBO }}$ | Emitter-Base Breakdown Voltage | $\mathrm{I}_{\mathrm{E}}=10 \mu \mathrm{~A}, \mathrm{I}_{\mathrm{C}}=0$ | 5.0 |  | V |
| $\mathrm{I}_{\mathrm{BL}}$ | Base Cutoff Current | $\mathrm{V}_{\mathrm{CE}}=30 \mathrm{~V}, \mathrm{~V}_{\mathrm{BE}}=3.0 \mathrm{~V}$ |  | 50 | nA |
| $\mathrm{I}_{\mathrm{CEX}}$ | Collector Cutoff Current | $\mathrm{V}_{\mathrm{CE}}=30 \mathrm{~V}, \mathrm{~V}_{\mathrm{BE}}=3.0 \mathrm{~V}$ |  | 50 | nA |

ON CHARACTERISTICS

| $\mathrm{h}_{\mathrm{FE}}$ | DC Current Gain * | $\mathrm{I}_{\mathrm{C}}=0.1 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=1.0 \mathrm{~V}$ | 60 |  |  |
| :--- | :--- | :--- | :---: | :---: | :---: |
|  |  | $\mathrm{I}_{\mathrm{C}}=1.0 \mathrm{~mA}, \mathrm{~V}_{\mathrm{C}}=1.0 \mathrm{~V}$ | 80 |  |  |
|  |  | $\mathrm{I}_{\mathrm{C}}=10 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=1.0 \mathrm{~V}$ | 100 | 300 |  |
|  |  | $\mathrm{I}_{\mathrm{C}}=50 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=1.0 \mathrm{~V}$ | 60 |  |  |
|  |  | $\mathrm{I}_{\mathrm{C}}=100 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=1.0 \mathrm{~V}$ | 30 |  |  |
|  |  | $\mathrm{I}_{\mathrm{C}}=10 \mathrm{~mA}, \mathrm{I}_{\mathrm{B}}=1.0 \mathrm{~mA}$ |  | 0.25 | V |
|  |  | $\mathrm{I}_{\mathrm{CE} \text { (sat) }}$ | Collector-Emitter Saturation Voltage |  |  |
|  |  | $\mathrm{I}_{\mathrm{C}}=50 \mathrm{~mA}, \mathrm{I}_{\mathrm{B}}=5.0 \mathrm{~mA}$ |  | 0.4 | V |
| $\mathrm{~V}_{\mathrm{BE} \text { (sat) }}$ | Base-Emitter Saturation Voltage | $\mathrm{I}_{\mathrm{C}}=10 \mathrm{~mA}, \mathrm{I}_{\mathrm{B}}=1.0 \mathrm{~mA}$ | 0.65 | 0.85 | V |
|  |  | $\mathrm{I}_{\mathrm{C}}=50 \mathrm{~mA}, \mathrm{I}_{\mathrm{B}}=5.0 \mathrm{~mA}$ |  | 0.95 | V |

SMALL SIGNAL CHARACTERISTICS

| $\mathrm{f}_{\mathrm{T}}$ | Current Gain - Bandwidth Product | $\mathrm{I}=10 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=20 \mathrm{~V}$, <br> $\mathrm{f}=100 \mathrm{MHz}$ | 250 |  | MHz |
| :--- | :--- | :--- | :---: | :---: | :---: |
| $\mathrm{C}_{\text {obo }}$ | Output Capacitance | $\mathrm{V}_{\mathrm{CB}}=5.0 \mathrm{~V}, \mathrm{I}_{\mathrm{E}}=0$, <br> $\mathrm{f}=100 \mathrm{kHz}$ |  | 4.5 | pF |
| $\mathrm{C}_{\text {ibo }}$ | Input Capacitance | $\mathrm{V}_{E B}=0.5 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=0$, <br> $\mathrm{f}=100 \mathrm{kHz}$ | 10.0 <br> NF Noise Figure | $\mathrm{I}=100 \mu \mathrm{C}, \mathrm{V}_{\mathrm{CE}}=5.0 \mathrm{~V}$, <br> $\mathrm{R}_{\mathrm{S}}=1.0 \mathrm{k} \Omega, \mathrm{f}=10 \mathrm{~Hz}$ to 15.7 kHz | pF |

## SWITCHING CHARACTERISTICS

| $\mathrm{t}_{\mathrm{d}}$ | Delay Time | $\mathrm{V}_{\mathrm{CC}}=3.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{BE}}=0.5 \mathrm{~V}$, | 35 | ns |
| :---: | :---: | :---: | :---: | :---: |
| $t_{r}$ | Rise Time | $\mathrm{I}_{\mathrm{C}}=10 \mathrm{~mA}, \mathrm{I}_{\mathrm{B} 1}=1.0 \mathrm{~mA}$ | 35 | ns |
| $\mathrm{t}_{\text {s }}$ | Storage Time | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=3.0 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=10 \mathrm{~mA} \\ & \mathrm{I}_{\mathrm{B} 1}=\mathrm{I}_{\mathrm{B} 2}=1.0 \mathrm{~mA} \end{aligned}$ | 225 | ns |
| $\mathrm{t}_{\mathrm{f}}$ | Fall Time |  | 75 | ns |

*Pulse Test: Pulse Width $\leq 300 \mu$ s, Duty Cycle $\leq 2.0 \%$
NOTE: All voltages $(\mathrm{V})$ and currents $(\mathrm{A})$ are negative polarity for PNP transistors.

## Spice Model

PNP (Is=1.41f Xti=3 Eg=1.11 Vaf=18.7 $\mathrm{Bf}=180.7 \mathrm{Ne}=1.5 \mathrm{Ise}=0 \quad \mathrm{Ikf}=80 \mathrm{~m} \quad \mathrm{Xtb}=1.5 \quad \mathrm{Br}=4.977 \mathrm{Nc}=2 \quad \mathrm{Isc}=0 \quad \mathrm{lkr}=0$ $\mathrm{Rc}=2.5 \mathrm{Cjc}=9.728 \mathrm{p} \mathrm{Mj}=.5776 \mathrm{Vjc}=.75 \mathrm{Fc}=.5 \mathrm{Cje}=8.063 \mathrm{p} \mathrm{Mje}=.3677 \mathrm{Vje}=.75 \mathrm{Tr}=33.42 \mathrm{n} \mathrm{Tf}=179.3 \mathrm{p} \mathrm{ltf}=.4 \mathrm{Vtf}=4$ $X t f=6 \quad R b=10)$

## Typical Characteristics




Base-Emitter Saturation



Collector-Cutoff Current vs Ambient Temperature







## TRADEMARKS

The following are registered and unregistered trademarks Fairchild Semiconductor owns or is authorized to use and is not intended to be an exhaustive list of all such trademarks.

| ACEx ${ }^{\text {TM }}$ | FASTr ${ }^{\text {TM }}$ | PowerTrench ${ }^{\text {® }}$ | SyncFET ${ }^{\text {TM }}$ |
| :---: | :---: | :---: | :---: |
| Bottomless ${ }^{\text {TM }}$ | GlobalOptoisolator ${ }^{\text {TM }}$ | QFET ${ }^{\text {TM }}$ | TinyLogic ${ }^{\text {TM }}$ |
| Coolfet ${ }^{\text {TM }}$ | GTO $^{\text {™ }}$ | QS ${ }^{\text {TM }}$ | UHC'M |
| CROSSVOLT ${ }^{\text {TM }}$ | HiSeCm | QT Optoelectronics ${ }^{\text {TM }}$ | VCX ${ }^{\text {TM }}$ |
| DOME ${ }^{\text {™ }}$ | ISOPLANAR ${ }^{\text {TM }}$ | Quiet Series ${ }^{\text {™ }}$ |  |
| $\mathrm{E}^{2} \mathrm{CMOS}^{\text {TM }}$ | MICROWIRE ${ }^{\text {TM }}$ | SILENT SWITCHER ${ }^{\circledR}$ |  |
| EnSigna ${ }^{\text {TM }}$ | OPTOLOGIC ${ }^{\text {TM }}$ | SMART START ${ }^{\text {TM }}$ |  |
| FACT ${ }^{\text {m }}$ | OPTOPLANAR ${ }^{\text {TM }}$ | SuperSOTTM-3 |  |
| FACT Quiet Series ${ }^{\text {TM }}$ | PACMAN ${ }^{\text {TM }}$ | SuperSOT™-6 |  |
| FAST ${ }^{\text {® }}$ | POP ${ }^{\text {TM }}$ | SuperSOT™-8 |  |

## DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

## LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUTTHE EXPRESS WRITTENAPPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in significant injury to the user.
2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

## PRODUCT STATUS DEFINITIONS

Definition of Terms

| Datasheet Identification | Product Status | Definition |
| :--- | :--- | :--- |
| Advance Information | Formative or <br> In Design | This datasheet contains the design specifications for <br> product development. Specifications may change in <br> any manner without notice. |
| Preliminary | First Production | This datasheet contains preliminary data, and <br> supplementary data will be published at a later date. <br> Fairchild Semiconductor reserves the right to make <br> changes at any time without notice in order to improve <br> design. |
| No Identification Needed | Full Production | This datasheet contains final specifications. Fairchild <br> Semiconductor reserves the right to make changes at <br> any time without notice in order to improve design. |
| Obsolete | Not In Production | This datasheet contains specifications on a product <br> that has been discontinued by Fairchild semiconductor. <br> The datasheet is printed for reference information only. |

